# -2A / -30V Bipolar transistor

## 2SB1714

#### Applications

Low frequency amplification, driver

#### Features

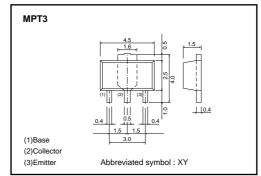
- 1) Collector current is high.
- 2) Low collector-emitter saturation voltage.

( $VCE(sat) \le -370mV$ , at Ic = -1.5A, IB = -75mA)

#### Structure

PNP epitaxial planar silicon transistor

#### ●External dimensions (Unit : mm)



#### ● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	-30	V	
Collector-emitter voltage		Vceo	-30	V	
Emitter-base voltage		Vево	-6	V	
Collector current	DC	lc	-2	A	
	Pulse	Іср	<b>-4</b> *1		
Power dissipation		Pc	0.5 *2	W	
		PC	2 *3		
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to +150	°C	

### Packaging specifications

	Package	MPT3
	Packaging type	Taping
	Code	T100
Part No.	Basic ordering unit (pieces)	1000
2SB1714		0

- \*1 Pw=1ms, Pulsed.
  \*2 Each terminal mounted on a recommended land.
  \*3 Mounted on a 40×40×0.7mm ceramic board.

#### ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BVceo	-30	_	-		Ic= -1mA
Collector-base breakdown voltage	ВУсво	-30	_	_	V	Ic= -10μA
Emitter-base breakdown voltage	ВVево	-6	_	_		I <sub>E</sub> = -10μA
Collector cut-off current	Ісво	_	_	-100	nA	VcB= -30V
Emitter cut-off current	ІЕВО	_	_	-100		V <sub>EB</sub> = -6V
Collector-emitter saturation voltage	VcE(sat) *	_	-180	-370	mV	Ic/I <sub>B</sub> = -1.5A/ -75A
DC current gain	hfe	270	_	680	_	Vce= -2V, Ic= -200mA
Transition frequency	f⊤	_	280	_	MHz	Vc= -2V, I=200mA , f=100MHz
Collector output capacitance	Cob	_	20	_	pF	Vcb= -10V , Ie=0mA , f=1MHz

<sup>\*</sup> Pulsed

#### Electrical characteristics curves

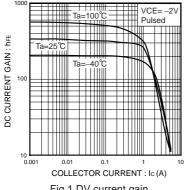


Fig.1 DV current gain vs. collector current

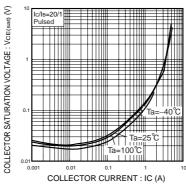


Fig.2 Collector-emitter saturation voltage vs. collector current

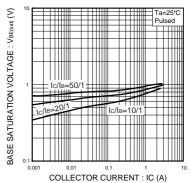


Fig.3 Base-emitter saturation voltage vs. collectir current

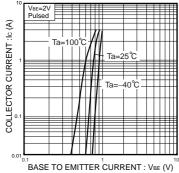


Fig.4 Grounded emitter propagation characteristics

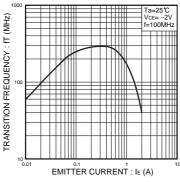
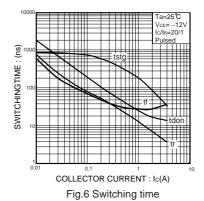


Fig.5 Gain bandwidth product vs. emitter curent



EMITTER TO BASE VOLTAGE: VBE (V)
COLLECTOR TO BASE VOLTAGE: VBE (V)
COLLECTOR TO BASE VOLTAGE: VBE (V)

Fig.7 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

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